

RF Driver Amplifier 250 - 4000 MHz

Rev. V1

Features

- Output Intercept Point of +42 dBm over a 20 dB Input Power Range
- Broadband Operation
- Lead-Free SOT-89 Package
- Halogen-Free “Green” Mold Compound
- RoHS* Compliant and 260°C Reflow Compatible
- Class 2 ESD Rating

Description

The MAAM-009560 RF driver amplifier is a GaAs MMIC which exhibits exceptional linearity performance over a >20 dB dynamic range, as well as featuring high gain in a lead-free miniature SOT-89 surface mount plastic package. The device is biased with a single +5 volt supply and consumes 225 mA typically.

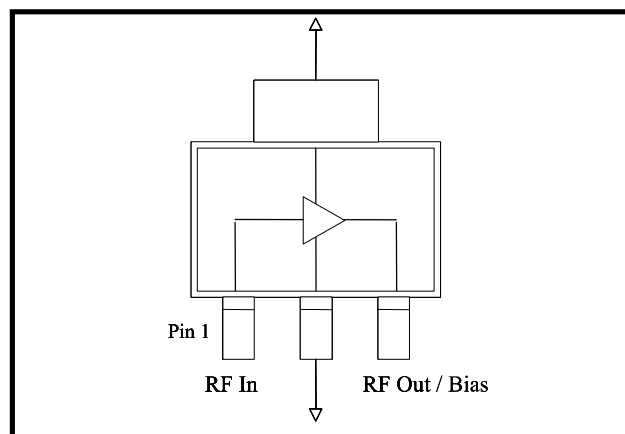
The MAAM-009560 is fabricated using an HBT process to realize low current and high linearity. The process features full passivation for increased performance and reliability.

Ordering Information ^{1,2}

Part Number	Package
MAAM-009560-000000	Bulk Packaging
MAAM-009560-TR3000	3000 piece reel
MAAM-009560-001SMB	Sample Board

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts.

Functional Schematic



Pin Configuration

Pin No.	Function	Pin No.	Function
1	RF Input	3	RF Output/Bias
2	Ground		

Maximum Operating Conditions ³

Parameter	Maximum Operating Conditions
Junction Temperature ⁴	170 °C
RF Output Power	28 dBm
Operating Temperature	-40 °C to +85 °C

3. These operating conditions will ensure MTTF > 1 x 10⁶ hours.

4. Junction Temperature (T_J) = $T_A + \Theta_{jc} * ((V * I) - (P_{OUT} - P_{IN}))$

Typical thermal resistance (Θ_{jc}) = 47° C/W

a) For $T_A = 25^\circ\text{C}$,

$T_J = 73^\circ\text{C}$ @ 5 V, 225 mA, $P_{OUT} = 20$ dBm, $P_{IN} = 5$ dBm

b) For $T_A = 85^\circ\text{C}$,

$T_J = 123^\circ\text{C}$ @ 5 V, 180 mA, $P_{OUT} = 20$ dBm, $P_{IN} = 5.5$ dBm

Absolute Maximum Ratings ^{5,6}

Parameter	Absolute Maximum
RF Output Power	29 dBm
Voltage	6 volts
Storage Temperature	-65 °C to +150 °C
Junction Temperature	210 °C

5. Exceeding any one or combination of these limits may cause permanent damage to this device.

6. M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.

* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

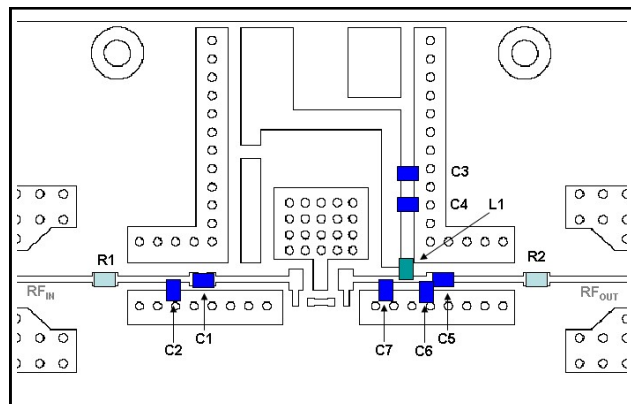
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Electrical Specifications: Freq. = 2140 MHz, $T_A = 25^\circ\text{C}$, $V_{CC} = +5\text{ V}$, $Z_0 = 50\ \Omega$

Parameter	Units	Min.	Typ.	Max.
Gain	dB	14	15	—
Noise Figure	dB	—	3	—
Input Return Loss	dB	—	15	—
Output Return Loss	dB	—	17	—
Output P1dB	dBm	—	28.5	—
Output IP3	dBm	40	42	—
Quiescent Current	mA	—	220	—
Current ($P_{IN} = 0\text{ dBm}$)	mA	—	225	325

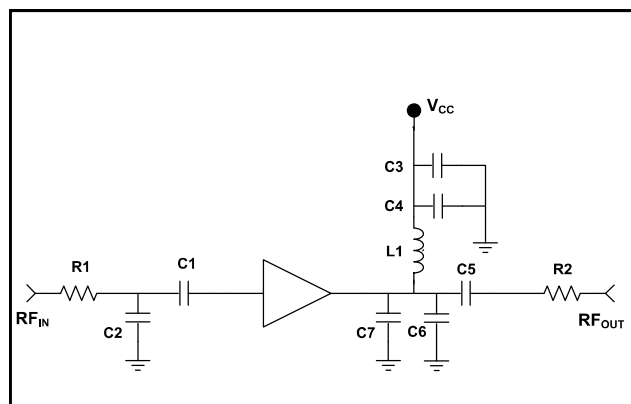
2140 MHz PCB Layout



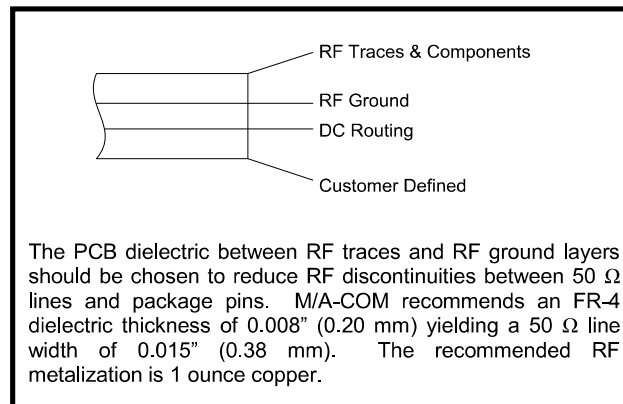
Parts List

Part	Value	Case Style
C1	1.8 pF	0402
C2	2.2 pF	0402
C3	0.1 μF	0402
C4	1000 pF	0402
C5	39 pF	0402
C6	1 pF	0402
C7	2 pF	0402
L1	3.6 nH	0402
R1, R2	0 Ω	0402

2140 Schematic

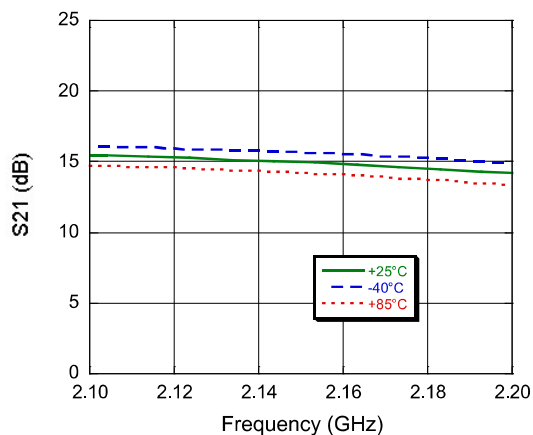


Cross Section View

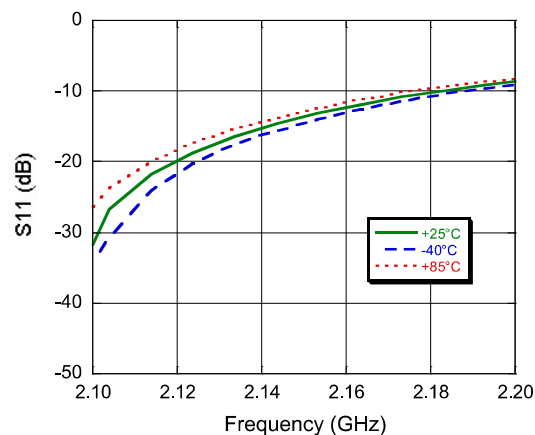


Typical Performance Curves, 2140 MHz Configuration

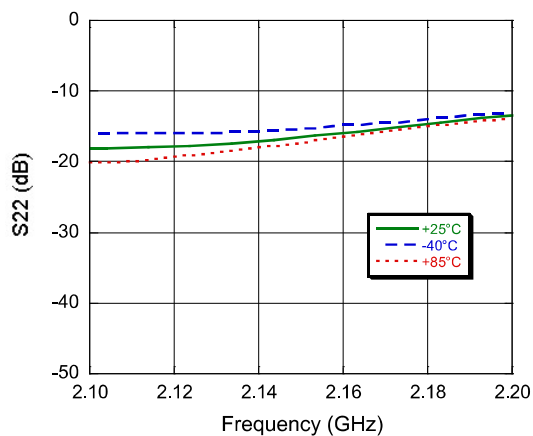
Gain



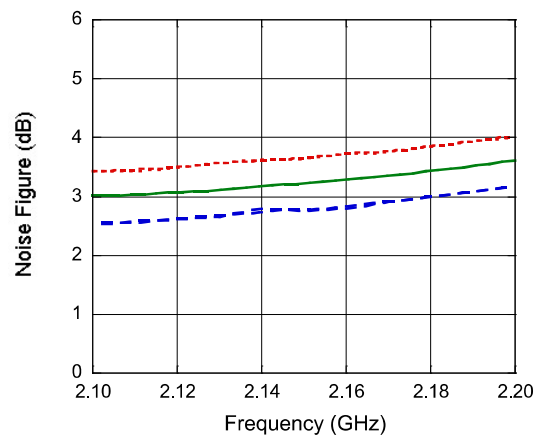
Input Return Loss



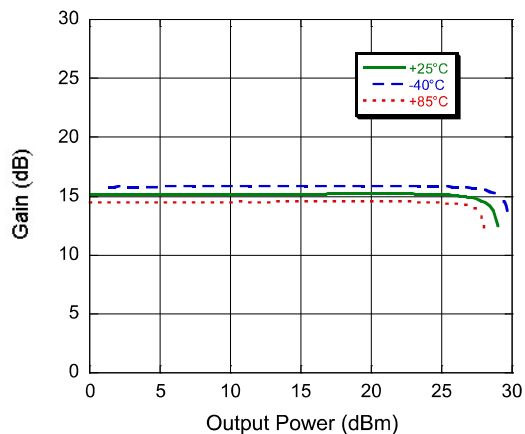
Output Return Loss



Noise Figure



P1dB



Output IP3

